

## **KTC3875**

# $\begin{array}{c} 0.15A\,,\,60V\\ NPN\,Plastic\,Encapsulated\,Transistor \end{array}$

RoHS Compliant Product

A suffix of "-C" specifies halogen & lead-free

### **FEATURES**

- High h<sub>FE</sub>
- · Low noise
- Complementary to KTA1504

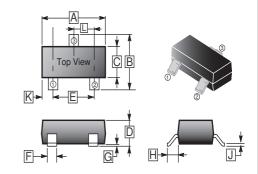
## **CLASSIFICATION OF hFE**

Product-Rank	KTC3875-O	KTC3875-Y	KTC3875-GR	KTC3875-BL	
Range	70~140 120~240		200~400	350~700	
Marking Code	ALO	ALY	ALG	ALL	

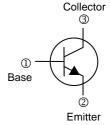
### **PACKAGE INFORMATION**

Package	MPQ	Leader Size		
SOT-23	3К	7 inch		

### **SOT-23**



REF.	Millimeter		REF.	Millimeter		
	Min.	Max.	KEF.	Min.	Max.	
Α	2.80	3.04	G	0.09	0.18	
В	2.10	2.55	Η	0.45	0.60	
С	1.20	1.40	J	0.08	0.177	
D	0.89	1.15	K	0.6 REF.		
Е	1.78	2.04	L	0.89	1.02	
F	0.30	0.50				



## **ABSOLUTE MAXIMUM RATINGS** (T<sub>A</sub>=25°C unless otherwise specified)

Parameter	Symbol	Ratings	Unit	
Collector to Base Voltage	$V_{CBO}$	60	V	
Collector to Emitter Voltage	$V_{CEO}$	50	V	
Emitter to Base Voltage	$V_{EBO}$	5	V	
Collector Current - Continuous	Ic	150	mA	
Collector Power Dissipation	Pc	150	mW	
Junction, Storage Temperature	$T_{J}, T_{STG}$	150, -55~150	°C	

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub>=25°C unless otherwise specified)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Collector to Base Breakdown Voltage	$V_{(BR)CBO}$	60	-	-	V	I <sub>C</sub> =100μA, I <sub>E</sub> =0
Collector to Emitter Breakdown Voltage	$V_{(BR)CEO}$	50	-	-	V	$I_C=1$ mA, $I_B=0$
Emitter to Base Breakdown Voltage	$V_{(BR)EBO}$	5	-	-	V	I <sub>E</sub> =100μA, I <sub>C</sub> =0
Collector Cut-Off Current	I <sub>CBO</sub>	-	-	0.1	μΑ	$V_{CB}=60V$ , $I_{E}=0$
Emitter Cut-Off Current	I <sub>EBO</sub>	-	-	0.1	μΑ	$V_{EB}=5V$ , $I_{C}=0$
DC Current Gain	h <sub>FE</sub>	70	-	700		V <sub>CE</sub> =6V, I <sub>C</sub> =2mA
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	-	0.1	0.25	V	I <sub>C</sub> =100mA, I <sub>B</sub> =10mA
Base to Emitter Saturation Voltage	$V_{BE(sat)}$	-	-	1	V	I <sub>C</sub> =100mA, I <sub>B</sub> =10mA
Transition Frequency	f⊤	80	-	-	MHz	V <sub>CE</sub> =10V, I <sub>C</sub> =1mA
Collector output capacitance	$C_ob$	-	2.0	3.5	pF	Vcb=10V, Ie=0, f=1MHz
Noise figure	NF	-	1	10	dB	VcE=6V, Ic=0.1mA, Rg=10kΩ, f=1KHz

http://www.SeCoSGmbH.com/

Any changes of specification will not be informed individually.

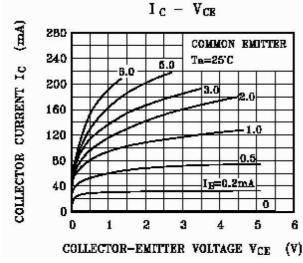
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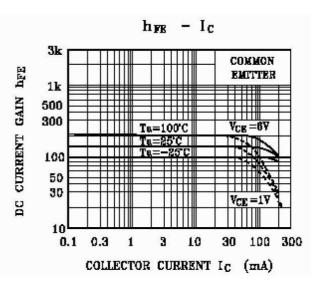


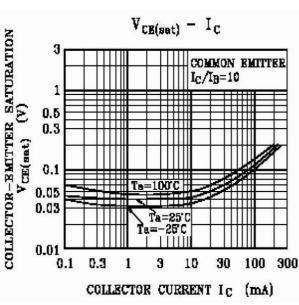
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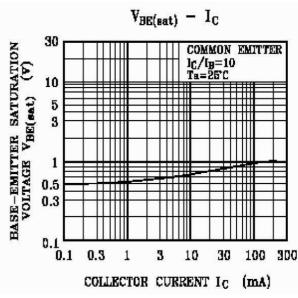
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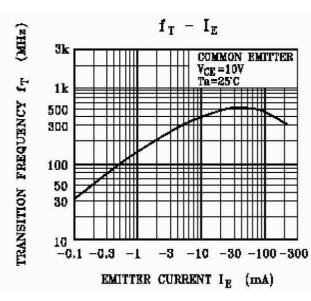
### **CHARACTERISTIC CURVES**

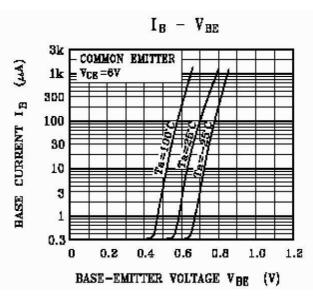












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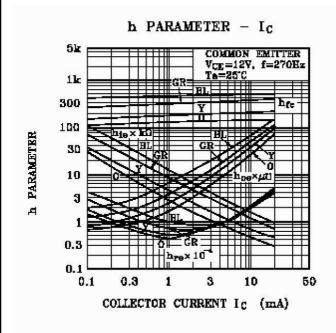
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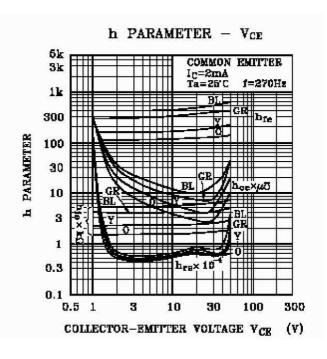


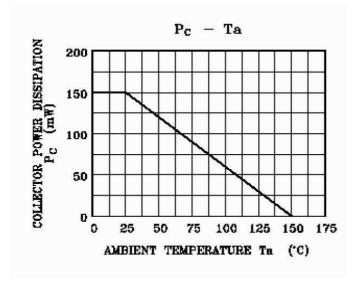
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